NSN 5961-01-408-6777

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-408-6777 **Inclosure Material:** Glass **Overall Length:** 4.25 millimeters **Terminal Length:** 25.4 millimeters **Overall Diameter:** 1.85 millimeters **End Application:** 6625-01-363-6212 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Sod-27 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 10.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 250.00 milliamperes forward current, average blank **Power Rating Per Characteristic:** 330.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No